

Optocoupler, Phototransistor Output, no Base Connection



i179004-14



FEATURES

- Isolation test voltage, 5000 V_{RMS}
- No base terminal connection for improved common mode interface immunity
- Long term stability
- Industry standard dual-in-line package
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912


RoHS
COMPLIANT

AGENCY APPROVALS

- UL file no. E52744
- cUL tested to CSA 22.2 bulletin 5A
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1
- BSI: EN 60065, EN 60950-1
- FIMKO
- CQC

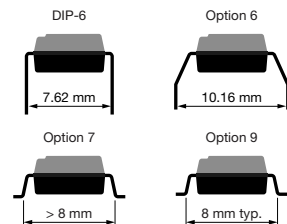
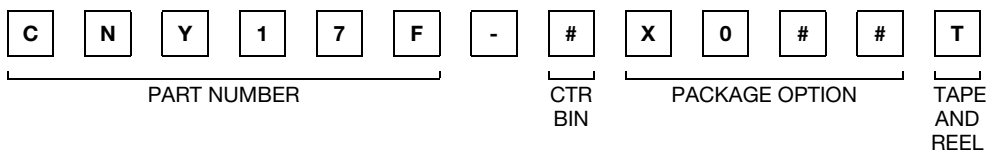
DESCRIPTION

The CNY17F is an optocoupler consisting of a gallium arsenide infrared emitting diode optically coupled to a silicon planar phototransistor detector in a plastic plug-in DIP-6 package.

The coupling device is suitable for signal transmission between two electrically separated circuits. The potential difference between the circuits to be coupled is not allowed to exceed the maximum permissible reference voltages.

In contrast to the CNY17 series, the base terminal of the F type is not connected, resulting in a substantially improved common-mode interference immunity.

ORDERING INFORMATION



AGENCY CERTIFIED/PACKAGE	CTR (%)			
	40 to 80	63 to 125	100 to 200	160 to 320
UL, cUL, BSI, FIMKO				
DIP-6	CNY17F-1	CNY17F-2	CNY17F-3	CNY17F-4
DIP-6, 400 mil, option 6	CNY17F-1X006	CNY17F-2X006	CNY17F-3X006	CNY17F-4X006
SMD-6, option 7	CNY17F-1X007 ⁽¹⁾	CNY17F-2X007T ⁽¹⁾	CNY17F-3X007T ⁽¹⁾	CNY17F-4X007T ⁽¹⁾
SMD-6, option 9	CNY17F-1X009T ⁽¹⁾	CNY17F-2X009T ⁽¹⁾	CNY17F-3X009T ⁽¹⁾	CNY17F-4X009T ⁽¹⁾
VDE, UL, cUL, BSI, FIMKO				
DIP-6	CNY17F-1X001	CNY17F-2X001	CNY17F-3X001	CNY17F-4X001
DIP-6, 400 mil, option 6	CNY17F-1X016	CNY17F-2X016	CNY17F-3X016	CNY17F-4X016
SMD-6, option 7	CNY17F-1X017 ⁽¹⁾	CNY17F-2X017 ⁽¹⁾	CNY17F-3X017 ⁽¹⁾	CNY17F-4X017 ⁽¹⁾
SMD-6, option 9	CNY17F-1X019	CNY17F-2X019 ⁽¹⁾	CNY17F-3X019 ⁽¹⁾	-

Notes

- Additional options may be possible, please contact sales office.
- ⁽¹⁾ Also available in tubes; do not put T on end.



ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V_R	6	V
DC forward current		I_F	60	mA
Surge forward current	$t \leq 10\text{ }\mu\text{s}$	I_{FSM}	2.5	A
Power dissipation		P_{diss}	70	mW
OUTPUT				
Collector emitter breakdown voltage		BV_{CEO}	70	V
Collector current		I_C	50	mA
Collector peak current	$t_p/T = 0.5, t_p \leq 10\text{ ms}$	I_{CM}	100	mA
Output power dissipation		P_{diss}	150	mW
COUPLER				
Isolation test voltage between emitter and detector	$t = 1\text{ min}$	V_{ISO}	5000	V_{RMS}
Creepage distance			≥ 7	mm
Clearance distance			≥ 7	mm
Isolation thickness between emitter and detector			≥ 0.4	mm
Comparative tracking index per DIN IEC 112/VDE 0303, part 1			≥ 175	
Isolation resistance	$V_{IO} = 500\text{ V}$	R_{IO}	$\geq 10^{11}$	Ω
Storage temperature range		T_{stg}	- 55 to + 150	$^{\circ}\text{C}$
Ambient temperature range		T_{amb}	- 55 to + 110	$^{\circ}\text{C}$
Junction temperature		T_j	100	$^{\circ}\text{C}$
Soldering temperature ⁽¹⁾	2 mm from case, $\leq 10\text{ s}$	T_{sld}	260	$^{\circ}\text{C}$
Total power dissipation		P_{diss}	220	mW

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- Refer to reflow profile for soldering conditions for surface mounted parts (SMD). Refer to wave profile for soldering conditions for through hole parts (DIP).

ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	$I_F = 60\text{ mA}$		V_F		1.39	1.65	V
Breakdown voltage	$I_R = 10\text{ }\mu\text{A}$		V_{BR}	6			V
Reverse current	$V_R = 6\text{ V}$		I_R		0.01	10	μA
Capacitance	$V_R = 0\text{ V}, f = 1\text{ MHz}$		C_O		25		pF
OUTPUT							
Collector emitter capacitance	$V_{CE} = 5\text{ V}, f = 1\text{ MHz}$		C_{CE}		5.2		pF
Base collector capacitance	$V_{CE} = 5\text{ V}, f = 1\text{ MHz}$		C_{BC}		6.5		pF
Emitter base capacitance	$V_{CE} = 5\text{ V}, f = 1\text{ MHz}$		C_{EB}		7.5		pF
COUPLER							
Collector emitter, saturation voltage	$I_F = 10\text{ mA}, I_C = 2.5\text{ mA}$		V_{CEsat}		0.25	0.4	V
Coupling capacitance			C_C		0.6		pF
Collector emitter, leakage current	$V_{CE} = 10\text{ V}$	CNY17F-1	I_{CEO}		2	50	nA
		CNY17F-2	I_{CEO}		2	50	nA
		CNY17F-3	I_{CEO}		5	100	nA
		CNY17F-4	I_{CEO}		5	100	nA

Note

- Minimum and maximum values were tested requirements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.



CURRENT TRANSFER RATIO ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I_C/I_F	$I_F = 10\text{ mA}$	CNY17F-1	CTR	40		80	%
		CNY17F-2	CTR	63		125	%
		CNY17F-3	CTR	100		200	%
		CNY17F-4	CTR	160		320	%
	$I_F = 1\text{ mA}$	CNY17F-1	CTR	13	30		%
		CNY17F-2	CTR	22	45		%
		CNY17F-3	CTR	34	70		%
		CNY17F-4	CTR	56	90		%

Note

- Current transfer ratio I_C/I_F at $V_{CE} = 5\text{ V}$, $25\text{ }^{\circ}\text{C}$ and collector emitter leakage current by dash number.

SWITCHING CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
LINEAR OPERATION (without saturation)							
Turn-on time	$I_F = 10\text{ mA}$, $V_{CC} = 5\text{ V}$, $R_L = 75\text{ }\Omega$		t_{on}		3		μs
Rise time	$I_F = 10\text{ mA}$, $V_{CC} = 5\text{ V}$, $R_L = 75\text{ }\Omega$		t_r		2		μs
Turn-off time	$I_F = 10\text{ mA}$, $V_{CC} = 5\text{ V}$, $R_L = 75\text{ }\Omega$		t_{off}		2.3		μs
Fall time	$I_F = 10\text{ mA}$, $V_{CC} = 5\text{ V}$, $R_L = 75\text{ }\Omega$		t_f		2		μs
Cut-off frequency	$I_F = 10\text{ mA}$, $V_{CC} = 5\text{ V}$, $R_L = 75\text{ }\Omega$		f_{CO}		110		kHz
SWITCHING OPERATION (with saturation)							
Turn-on time	$I_F = 20\text{ mA}$	CNY17F-1	t_{on}		3		μs
	$I_F = 10\text{ mA}$	CNY17F-2	t_{on}		4.2		μs
		CNY17F-3	t_{on}		4.2		μs
		CNY17F-4	t_{on}		6		μs
Rise time	$I_F = 20\text{ mA}$	CNY17F-1	t_r		2		μs
	$I_F = 10\text{ mA}$	CNY17F-2	t_r		3		μs
		CNY17F-3	t_r		3		μs
		CNY17F-4	t_r		4.6		μs
Turn-off time	$I_F = 20\text{ mA}$	CNY17F-1	t_{off}		18		μs
	$I_F = 10\text{ mA}$	CNY17F-2	t_{off}		23		μs
		CNY17F-3	t_{off}		23		μs
		CNY17F-4	t_{off}		25		μs
Fall time	$I_F = 20\text{ mA}$	CNY17F-1	t_f		11		μs
	$I_F = 10\text{ mA}$	CNY17F-2	t_f		14		μs
		CNY17F-3	t_f		14		μs
		CNY17F-4	t_f		15		μs



95 10804-3

Fig. 1 - Test Circuit, Non-Saturated Operation



t_p	Pulse duration	t_s	Storage time
t_d	Delay time	t_f	Fall time
t_r	Rise time	$t_{off} (= t_s + t_f)$	Turn-off time
$t_{on} (= t_d + t_r)$	Turn-on time		

96 11698

Fig. 3 - Switching Times



95 10843

Fig. 2 - Test Circuit, Saturated Operation

TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^\circ\text{C}$, unless otherwise specified)

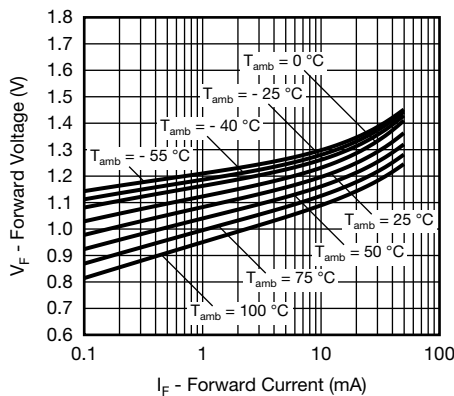


Fig. 4 - Forward Voltage vs. Forward Current



Fig. 5 - Collector Current vs. Collector Emitter Voltage (NS)



Fig. 6 - Collector Current vs. Collector Emitter Voltage (sat)



Fig. 9 - Normalized CTR (sat) vs. Ambient Temperature



Fig. 7 - Leakage Current vs. Ambient Temperature



Fig. 10 - Normalized CTR (NS) vs. Forward Current



Fig. 8 - Normalized CTR (NS) vs. Ambient Temperature



Fig. 11 - Normalized CTR (sat) vs. Forward Current



Fig. 12 - CTR Frequency vs. Phase Angle

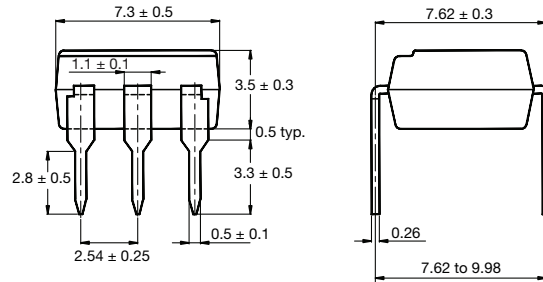


Fig. 13 - CTR Frequency vs. Collector Current



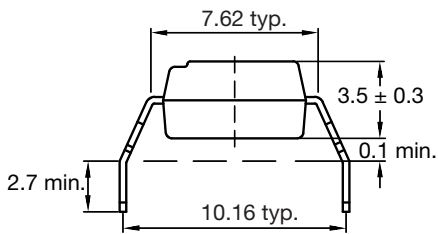
Fig. 14 - Switching Time vs. Load Resistance

PACKAGE DIMENSIONS in millimeters



22530

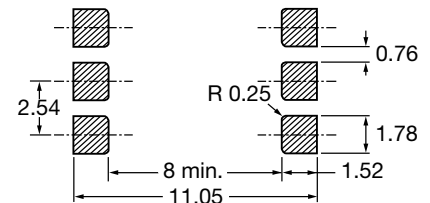
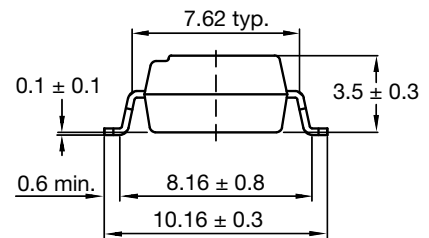
Option 6



Option 7



Option 9



20802-34

PACKAGE MARKING



Notes

- VDE logo is only marked on option 1 parts. Option information is not marked on the part.
- Tape and reel suffix (T) is not part of the package marking.



TUBE AND TAPE INFORMATION

DEVICES PER TUBE			
TYPE	UNITS/TUBE	TUBES/BOX	UNITS/BOX
DIP-6	50	40	2000



Fig. 15 - Tape and Reel Drawing, 1000 Units per Reel



Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9